



App. No. 09/653,156

#17C
Amdt
SDavis
3/5/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 09/653,156
Filing Date August 31, 2000
Inventor..... Vishnu K. Agarwal, et al
Assignee..... Micron Technology, Inc.
Group Art Unit..... 2813
Examiner Y. Huynh
Attorney's Docket No. MI22-1518
Title: Enhanced Surface Area Capacitor Fabrication Methods (as amended)

RESPONSE TO OCTOBER 15, 2002 OFFICE ACTION

To: Art Unit 2813
Assistant Commissioner for Patents
Washington, D.C. 20231

From: James E. Lake (Tel. 509-624-4276; Fax 509-838-3424)
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AMENDMENTS

In the Specification

Please replace the title with the following clean replacement title in accordance
with 37 C.F.R. §1.121(b)(1)(ii):

--Enhanced Surface Area Capacitor Fabrication Methods--

In the Claims

Please add new claim 27 in accordance with 37 C.F.R. 1.121(c)(1)(i). No marked up
version is required.

C1 SUB DI 17
17. (new) The method of claim 1 wherein the TiN forms a continuous layer within the
first electrode.

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